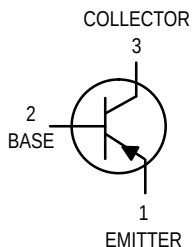
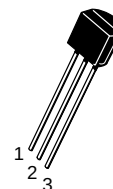


Switching Transistor

PNP Silicon



MPS3638A



CASE 29-04, STYLE 1
TO-92 (TO-226AA)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	–25	Vdc
Collector–Emitter Voltage	V_{CES}	–25	Vdc
Collector–Base Voltage	V_{CBO}	–25	Vdc
Emitter–Base Voltage	V_{EBO}	–4.0	Vdc
Collector Current — Continuous	I_C	–500	mA _{dc}
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625 5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5 12	Watts mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–55 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}^{(1)}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
----------------	--------	-----	-----	------

OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ($I_C = -100 \mu\text{A}_{dc}$, $V_{BE} = 0$)	$V_{(BR)CES}$	–25	—	Vdc
Collector–Emitter Sustaining Voltage ⁽²⁾ ($I_C = -10 \text{ mA}_{dc}$, $I_B = 0$)	$V_{CEO(sus)}$	–25	—	Vdc
Collector–Base Breakdown Voltage ($I_C = -100 \mu\text{A}_{dc}$, $I_E = 0$)	$V_{(BR)CBO}$	–25	—	Vdc
Emitter–Base Breakdown Voltage ($I_E = -100 \mu\text{A}_{dc}$, $I_C = 0$)	$V_{(BR)EBO}$	–4.0	—	Vdc
Collector Cutoff Current ($V_{CE} = -15 \text{ Vdc}$, $V_{BE} = 0$) ($V_{CE} = -15 \text{ Vdc}$, $V_{BE} = 0$, $T_A = -65^\circ\text{C}$)	I_{CES}	— —	–0.035 –2.0	μA_{dc}
Emitter Cutoff Current ($V_{EB} = -3.0 \text{ V}$, $I_C = 0$)	I_{EBO}	—	–35	nA
Base Current ($V_{CE} = -15 \text{ Vdc}$, $V_{BE} = 0$)	I_B	—	–0.035	μA_{dc}

- $R_{\theta JA}$ is measured with the device soldered into a typical printed circuit board.
- Pulse Test: Pulse Width $\leq 300 \mu\text{s}$; Duty Cycle $\leq 2.0\%$.

(Replaces MPS3638/D)

MPS3638A**ELECTRICAL CHARACTERISTICS** ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS(2)				
DC Current Gain ($I_C = -1.0\text{ mA}$, $V_{CE} = -10\text{ Vdc}$) ($I_C = -10\text{ mA}$, $V_{CE} = -10\text{ Vdc}$) ($I_C = -50\text{ mA}$, $V_{CE} = -1.0\text{ Vdc}$) ($I_C = -300\text{ mA}$, $V_{CE} = -2.0\text{ Vdc}$)	h_{FE}	80 100 100 20	— — — —	—
Collector–Emitter Saturation Voltage ($I_C = -50\text{ mA}$, $I_B = -2.5\text{ mA}$) ($I_C = -300\text{ mA}$, $I_B = -30\text{ mA}$)	$V_{CE(sat)}$	— —	–0.25 –1.0	Vdc
Base–Emitter Saturation Voltage ($I_C = -50\text{ mA}$, $I_B = -2.5\text{ mA}$) ($I_C = -300\text{ mA}$, $I_B = -30\text{ mA}$)	$V_{BE(sat)}$	— –0.80	–1.1 –2.0	Vdc

SMALL–SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product ($V_{CE} = -3.0\text{ Vdc}$, $I_C = -50\text{ mA}$, $f = 100\text{ MHz}$)	f_T	150	—	MHz
Output Capacitance ($V_{CB} = -10\text{ Vdc}$, $I_E = 0$, $f = 1.0\text{ MHz}$)	C_{obo}	—	10	pF
Input Capacitance ($V_{EB} = -0.5\text{ Vdc}$, $I_C = 0$, $f = 1.0\text{ MHz}$)	C_{ibo}	—	25	pF
Input Impedance ($I_C = -10\text{ mA}$, $V_{CE} = -10\text{ Vdc}$, $f = 1.0\text{ kHz}$)	h_{ie}	—	2000	k Ω
Voltage Feedback Ratio ($I_C = -10\text{ mA}$, $V_{CE} = -10\text{ Vdc}$, $f = 1.0\text{ kHz}$)	h_{re}	—	15	$\times 10^{-4}$
Small–Signal Current Gain ($I_C = -10\text{ mA}$, $V_{CE} = -10\text{ Vdc}$, $f = 1.0\text{ kHz}$)	h_{fe}	100	—	—
Output Admittance ($I_C = -10\text{ mA}$, $V_{CE} = -10\text{ Vdc}$, $f = 1.0\text{ kHz}$)	h_{oe}	—	1.2	mmhos

SWITCHING CHARACTERISTICS

Delay Time	$(V_{CC} = -10\text{ Vdc}$, $I_C = -300\text{ mA}$, $I_{B1} = -30\text{ mA}$)	t_d	—	20	ns
Rise Time		t_r	—	70	ns
Storage Time	$(V_{CC} = -10\text{ Vdc}$, $I_C = -300\text{ mA}$, $I_{B1} = -30\text{ mA}$, $I_{B2} = -30\text{ mA}$)	t_s	—	140	ns
Fall Time		t_f	—	70	ns
Turn–On Time	$(I_C = -300\text{ mA}$, $I_{B1} = -30\text{ mA}$)	t_{on}	—	75	ns
Turn–Off Time	$(I_C = -300\text{ mA}$, $I_{B1} = -30\text{ mA}$, $I_{B2} = 30\text{ mA}$)	t_{off}	—	170	ns

2. Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$; Duty Cycle $\leq 2.0\%$.

SWITCHING TIME EQUIVALENT TEST CIRCUIT

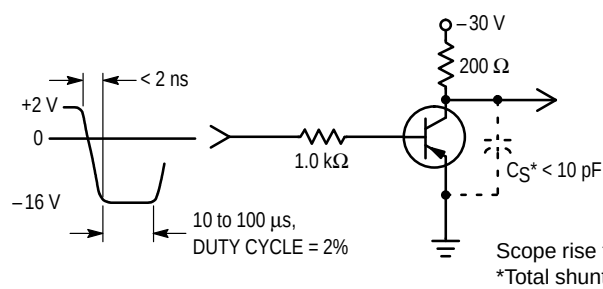


Figure 1. Turn-On Time

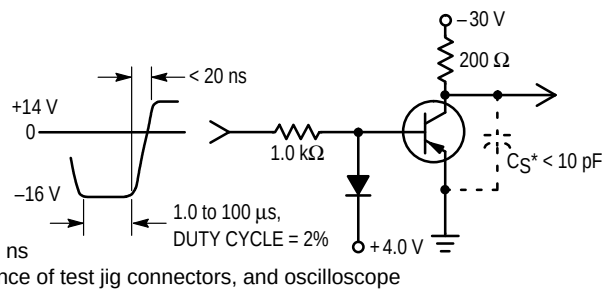


Figure 2. Turn-Off Time

TRANSIENT CHARACTERISTICS

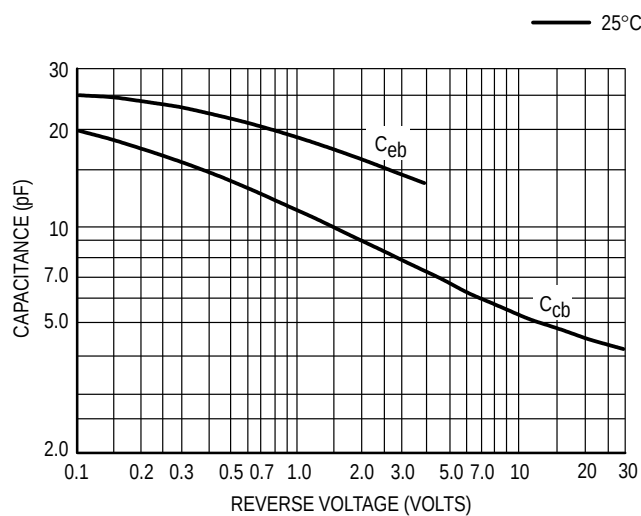


Figure 3. Capacitances

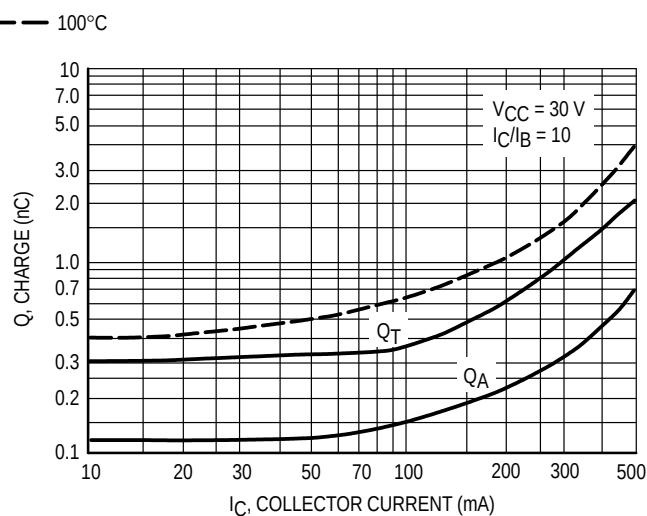


Figure 4. Charge Data

TRANSIENT CHARACTERISTICS (Continued)

— 25°C - - - 100°C

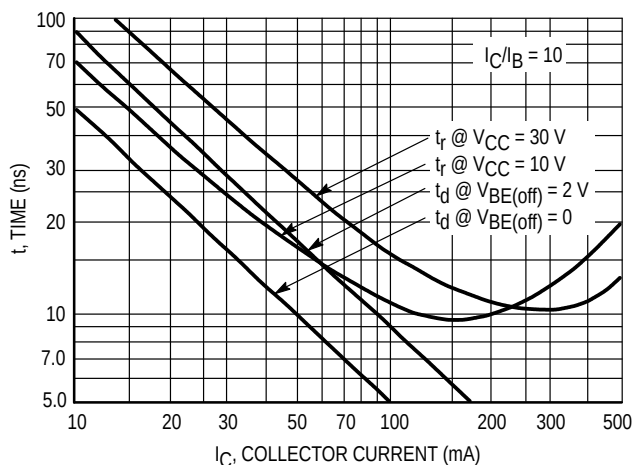


Figure 5. Turn-On Time

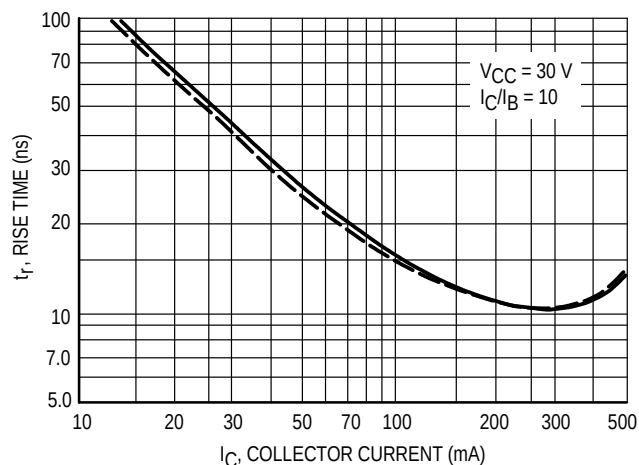


Figure 6. Rise Time

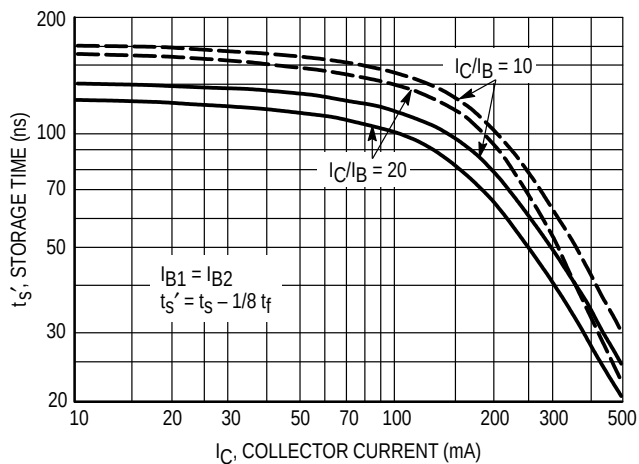


Figure 7. Storage Time

SMALL-SIGNAL CHARACTERISTICS

NOISE FIGURE

$$V_{CE} = -10 \text{ Vdc}, T_A = 25^\circ\text{C}$$

$$\text{Bandwidth} = 1.0 \text{ Hz}$$

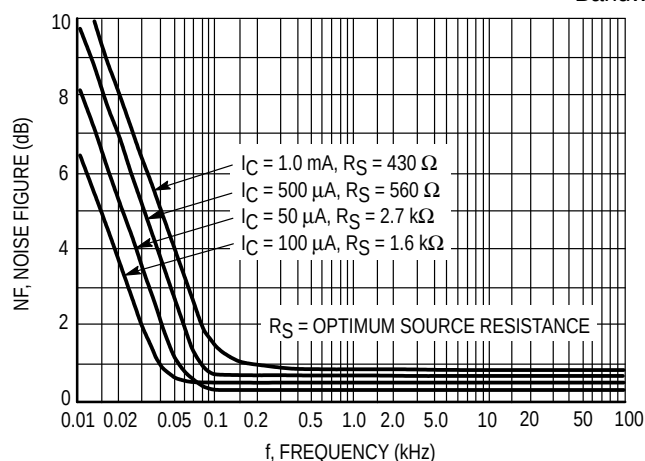


Figure 8. Frequency Effects

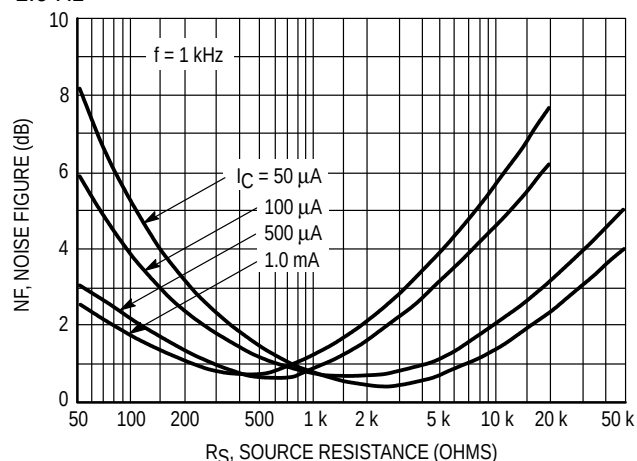


Figure 9. Source Resistance Effects

h PARAMETERS

$$V_{CE} = -10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_A = 25^\circ\text{C}$$

This group of graphs illustrates the relationship between h_{fe} and other "h" parameters for this series of transistors. To obtain these curves, a high-gain and a low-gain unit were

selected from the 2N4402 line, and the same units were used to develop the correspondingly-numbered curves on each graph.

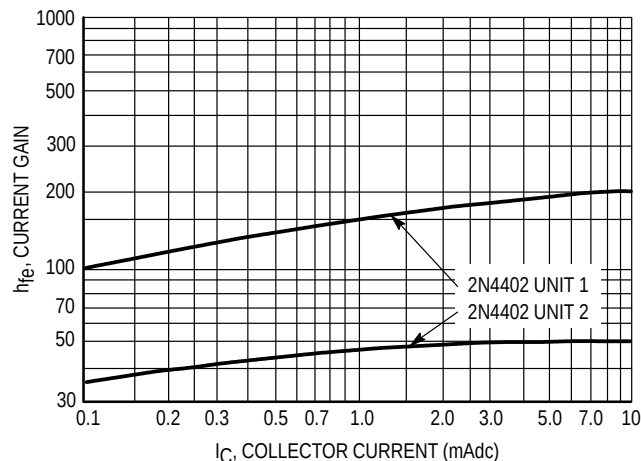


Figure 10. Current Gain

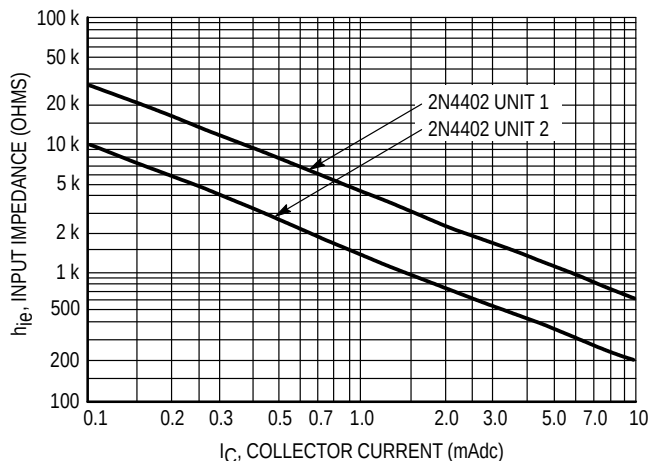


Figure 11. Input Impedance

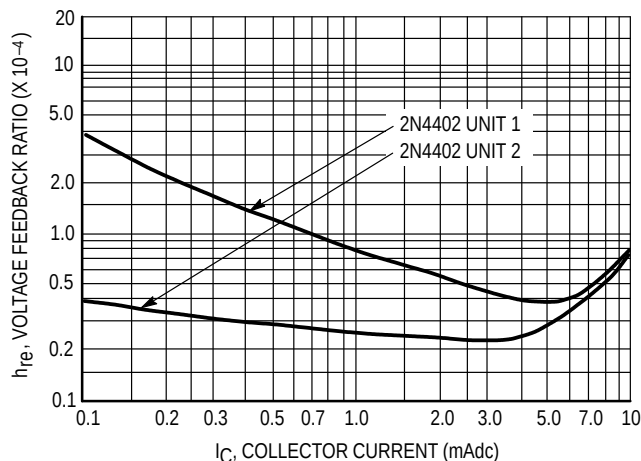


Figure 12. Voltage Feedback Ratio

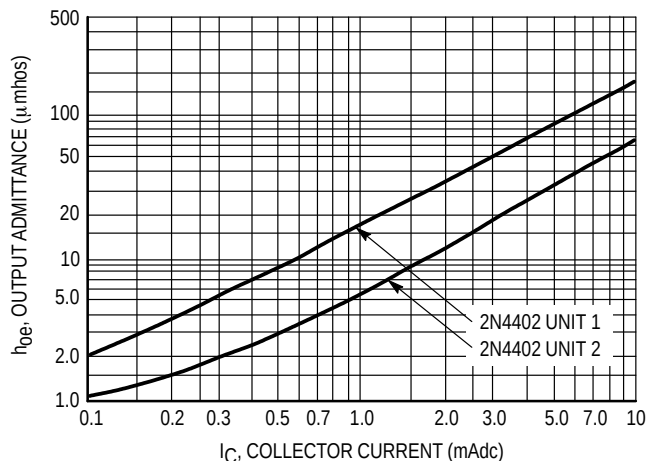


Figure 13. Output Admittance

STATIC CHARACTERISTICS

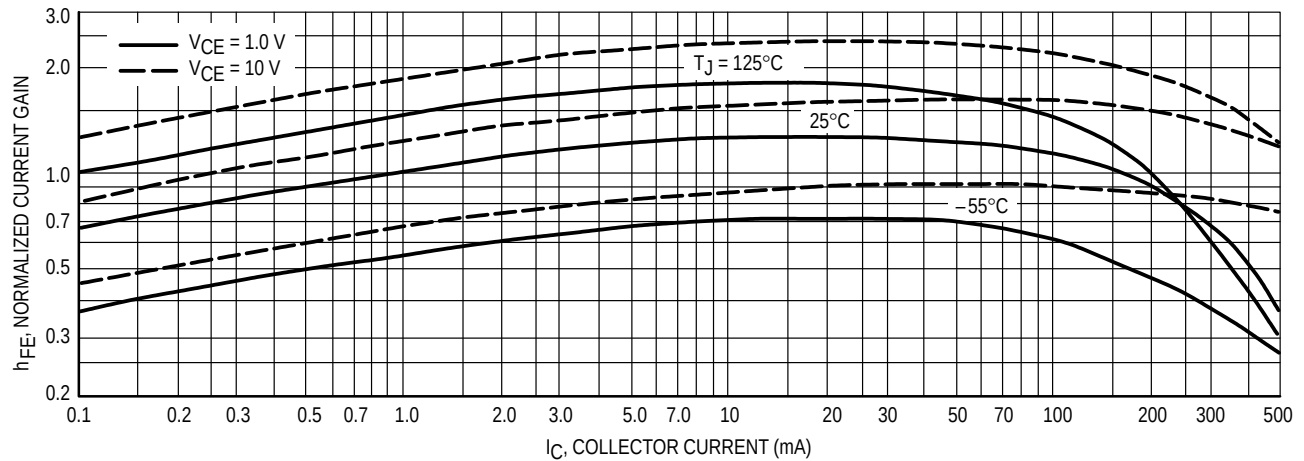


Figure 14. DC Current Gain

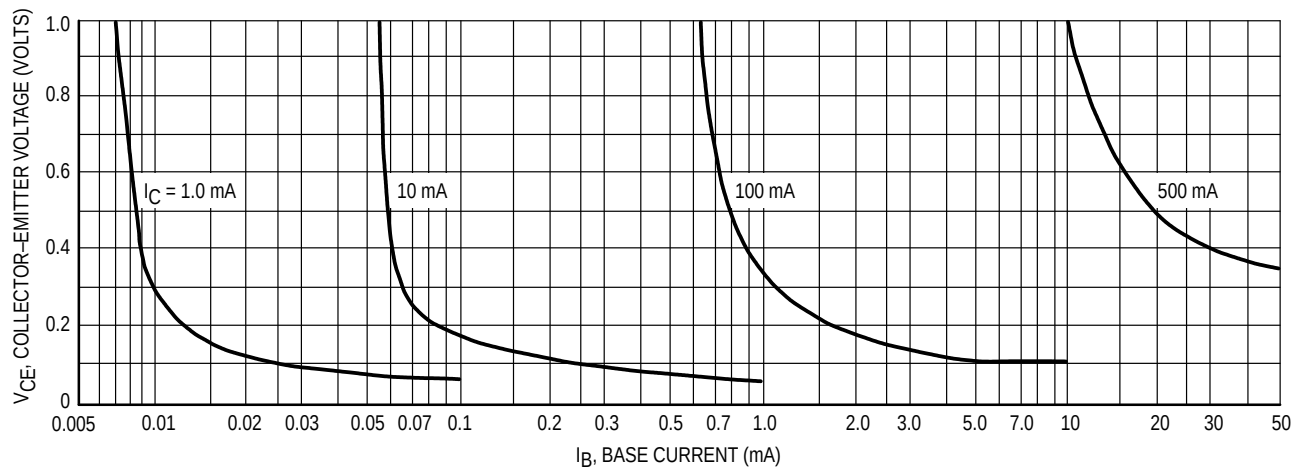


Figure 15. Collector Saturation Region

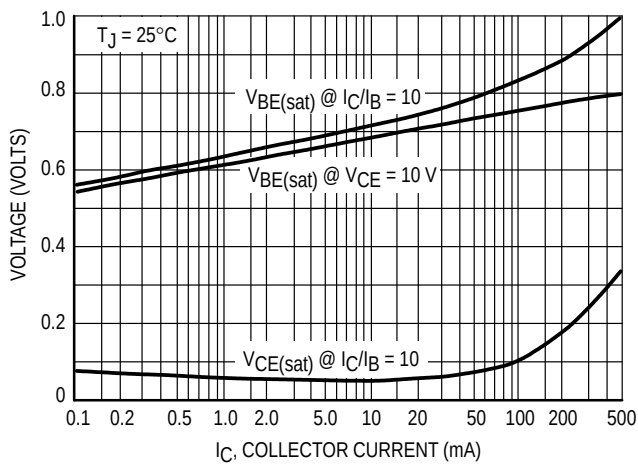


Figure 16. "On" Voltages

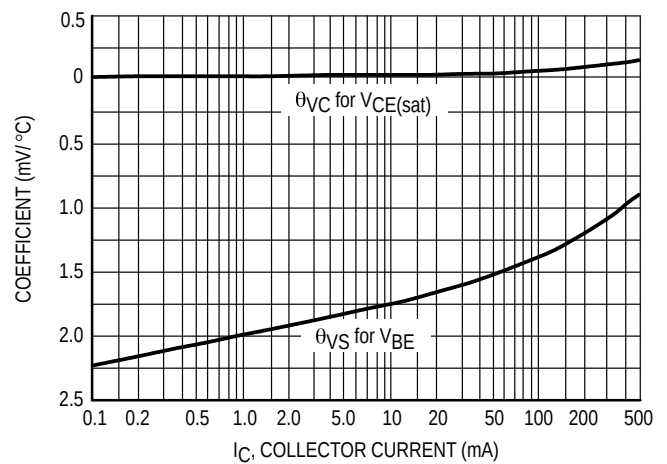
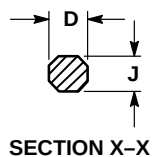
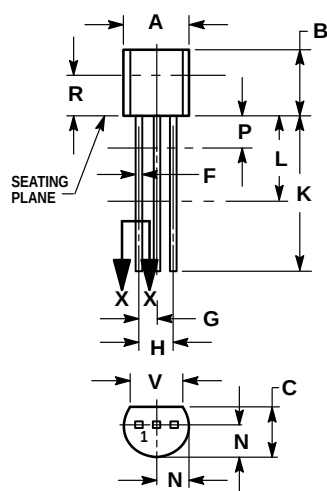


Figure 17. Temperature Coefficients

PACKAGE DIMENSIONS



**CASE 029-04
(TO-226AA)
ISSUE AD**

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.115	—	2.93	—
V	0.135	—	3.43	—

STYLE 1:

1. EMITTER
2. BASE
3. COLLECTOR

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Motorola data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and  are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

Mfax is a trademark of Motorola, Inc.

How to reach us:

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution;
P.O. Box 5405, Denver, Colorado 80217. 303-675-2140 or 1-800-441-2447

JAPAN: Nippon Motorola Ltd.: SPD, Strategic Planning Office, 4-32-1,
Nishi-Gotanda, Shinagawa-ku, Tokyo 141, Japan. 81-3-5487-8488

Mfax™: RMFAX0@email.sps.mot.com – TOUCHTONE 602-244-6609
– US & Canada ONLY 1-800-774-1848

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park,
51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298

INTERNET: <http://motorola.com/sps>

